NSN 5961-01-226-2097

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View Online at https://aerobasegroup.com/nsn/5961-01-226-2097 **Inclosure Material:** Plastic **Overall Length:** 1.230 inches **Overall Height:** 0.190 inches **Overall Width:** 0.420 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 breakdown voltage, collector-to-base, emitter open and 150.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 1.50 amperes source cutoff current **Power Rating Per Characteristic:** 1.5 watts small-signal input power, common-collector **Transfer Ratio:** 75.0 small-signal short-circuit forward current transfer ratio, common-base **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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